## PCS224 - Solid State Physics - Useful Formulas

$$\vec{F} = q\vec{E}$$

$$\vec{F} = q \left( \vec{v} \times \vec{B} \right)$$

$$|\vec{F}| = |q| |\vec{v}| |\vec{B}| \sin \theta$$

$$|\vec{E}|_{\text{plate}} = \frac{Q}{2A\epsilon_0} = \frac{\sigma}{2\epsilon_0}$$

$$K = mv^2/2$$

$$\Delta K + \Delta U = 0$$

$$\Delta U = q\Delta V$$

$$\Delta V = -\vec{E} \cdot \Delta \vec{x} \text{ or } -\vec{E} \cdot \Delta \vec{y}$$

$$|\Delta V| = |\vec{E}| |\Delta x| \text{ or } |\vec{E}| |\Delta y|$$

$$\Delta V = IR$$

$$P = I\Delta V = I^2 R = \frac{\Delta V^2}{R}$$

$$E = hf = hc/\lambda$$

$$f\lambda = c$$

$$hf = K_{\text{max}} + \phi$$

$$K_{\text{max}} = eV_{\text{stop}}$$

$$n_0 p_0 = n_i^2$$

$$I = \frac{\Delta Q}{\Delta t}$$

$$I = nqAv_d$$

$$J = I/A$$

$$J = \sigma \vec{E}$$

$$\vec{v}_{\text{dp}} = \mu_p \vec{E}$$

$$\vec{v}_{\text{dh}} = -\mu_n \vec{E}$$

$$\sigma = \frac{1}{\rho \vec{k}} e \left[ n\mu_n + p\mu_p \right]$$

$$R = \rho L/A = L/(\sigma A)$$

$$\Delta V_H = \frac{IB}{nqt_B} \text{ or } \Delta V_H = \frac{IB}{nqd}$$

$$E_n = \frac{-13.6 \text{ eV}}{1 + e^{\frac{E_F - E}{k_B T}}}$$

$$f_H(E) = 1 - f_F(E) = \frac{1}{1 + e^{\frac{E_F - E}{k_B T}}}$$

$$W$$

$$n_{0} = N_{C}e^{\frac{-(E_{C}-E_{F})}{k_{B}T}} = n_{i}e^{\frac{E_{F}-E_{Fi}}{k_{B}T}}$$

$$p_{0} = N_{V}e^{\frac{-(E_{C}-E_{V})}{k_{B}T}} = n_{i}e^{\frac{E_{Fi}-E_{Fi}}{k_{B}T}}$$

$$n_{i}^{2} = N_{C}N_{V}e^{\frac{-E_{g}}{k_{B}T}}$$

$$N_{d} - N_{a} = n_{0} - p_{0}$$

$$N_{C} = \frac{2.5 \times 10^{19}}{\text{cm}^{3}} \left(\frac{m_{n}^{*}}{m_{e}}\right)^{3/2} \left(\frac{T}{300 \text{ K}}\right)^{3/2}$$

$$N_{C}(T) = N_{C}(300 \text{ K}) \cdot \left(\frac{T}{300 \text{ K}}\right)^{3/2}$$

$$N_{V} = \frac{2.5 \times 10^{19}}{\text{cm}^{3}} \left(\frac{m_{p}^{*}}{m_{e}}\right)^{3/2} \left(\frac{T}{300 \text{ K}}\right)^{3/2}$$

$$N_{V}(T) = N_{V}(300 \text{ K}) \cdot \left(\frac{T}{300 \text{ K}}\right)^{3/2}$$

$$E_{C} - E_{F} = k_{B}T \ln \left(\frac{N_{C}}{n_{0}}\right)$$

$$E_{F} - E_{V} = k_{B}T \ln \left(\frac{N_{C}}{n_{0}}\right)$$

$$E_{F} = E_{Fi} + \frac{k_{B}T}{2} \ln \left(\frac{n_{0}}{n_{0}}\right)$$

$$E_{Fi} = E_{\text{mid-gap}} + \frac{3k_{B}T}{4} \ln \left(\frac{m_{p}^{*}}{m_{n}^{*}}\right)$$

$$V_{bi} = \frac{k_{B}T}{e} \ln \left(\frac{N_{a}N_{d}}{n_{i}^{2}}\right)$$

$$|\vec{E}|_{\text{max}} = \frac{eN_{d}x_{n}}{\epsilon_{s}} = \frac{eN_{A}x_{p}}{\epsilon_{s}} = \frac{2(V_{\text{bi}} + V_{R})}{W}$$

$$\epsilon_{s} = \kappa\epsilon_{0}$$

$$x_{n}N_{d} = x_{p}N_{A}$$

$$x_{n} = \sqrt{\frac{2\epsilon_{s}(V_{\text{bi}} + V_{R})}{e}} \left(\frac{N_{A}}{N_{d}}\right) \left(\frac{1}{N_{A} + N_{d}}\right)$$

$$W = \left[\frac{2\epsilon_{s}(V_{\text{bi}} + V_{R})}{e} \left(\frac{N_{A}}{N_{A}}\right) \left(\frac{1}{N_{A} + N_{d}}\right)\right]^{1/2}$$

$$C = \frac{Q}{\Delta V} = \frac{dQ}{dV} = \frac{\epsilon_s A}{d} = \frac{\epsilon_s A}{W}$$

$$C' = C/A$$

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$$V_{G} = \phi_{ms} + V_{ox} + \phi_s$$

$$V_{TN} = \phi_{ms} + \frac{t_{ox} \left( |Q'_{SD,max}| - Q'_{SS}| \right)}{\epsilon_{ox}} + 2|\phi_{Fp}|$$

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$$V_{TN} = \phi_{ms} + \frac{t_{ox} \left( |Q'_{SD,max}| + Q'_{SS} \right)}{\epsilon_{ox}} + \frac{t_{ox} \left( |Q'_{SD,max}| + Q'_{SS} \right)}{\epsilon_{ox}} + 2|\phi_{Fp}|$$

$$V_{TN} = \phi_{ms} + \frac{t_{ox} \left( |Q'_{SD,max}| + Q'_{SS} \right)}{\epsilon_{ox}} + \frac{t_{ox} \left( |Q'_{SD,max}| + Q'_{SD} \right)}{\epsilon_{ox}} + \frac{t_{ox} \left( |Q'_{SD,max}| + Q'_{SD} \right)}{\epsilon_{ox}} + \frac{t_{ox} \left( |Q'_{SD,max}| + Q'_{SD} \right)}{\epsilon_$$

If necessary, Figure 4.20 (Hall Effect) and Figure 6.21 (Metal-Semiconductor work functions) will be provided along with relevant equations

## Fundamental constants and units

$$e = 1.6 \times 10^{-19} \, \mathrm{C}$$

$$m_e = 9.1 \times 10^{-31} \, \mathrm{kg}$$

$$h = 6.64 \times 10^{-34} \, \mathrm{J} \cdot \mathrm{sec}$$

$$c = 3.0 \times 10^8 \, \frac{\mathrm{m}}{\mathrm{sec}}$$

$$hc = 1240 \, \mathrm{eV} \cdot \mathrm{nm}$$

$$k_B = 1.38 \times 10^{-23} \, \mathrm{J/K} = 8.617 \times 10^{-5} \, \mathrm{eV/K}$$

$$k_B T = 0.026 \, \mathrm{eV} \left( \frac{T}{300 \, \mathrm{K}} \right)$$

$$k_c = 9.0 \times 10^9 \, \frac{\mathrm{N} \cdot \mathrm{m}^2}{\mathrm{C}^2}$$

$$\epsilon_0 = 8.85 \times 10^{-12} \, \frac{\mathrm{F}}{\mathrm{m}} = 552000 \, \frac{\mathrm{e}}{\mathrm{V} \cdot \mathrm{cm}}$$

$$1 \, \mathrm{eV} = 1.6 \times 10^{-19} \, \mathrm{J}$$

$$1 \, \mathrm{N} = 1 \, \mathrm{kg} \, \frac{\mathrm{m}^2}{\mathrm{sec}^2}$$

$$1 \, \mathrm{W} = 1 \, \mathrm{J/s}$$

$$1 \, \mathrm{V} = 1 \, \mathrm{J/c}$$

$$1 \, \mathrm{A} = 1 \, \mathrm{C/sec}$$

$$1 \, \mathrm{T} = 1 \, \mathrm{kg/(C} \cdot \mathrm{sec}) = 1 \, \mathrm{V} \cdot \mathrm{sec/m}^2$$

$$1 \, \mathrm{F} = 1 \, \mathrm{C/V}$$

$$1 \, \mathrm{A} = 10^{-8} \, \mathrm{cm}$$

Table B.4 | Silicon, gallium arsenide, and germanium properties  $(T=300~\mathrm{K})$ 

Property	Si	GaAs	Ge
Atoms (cm <sup>-3</sup> )	$5.0\times10^{22}$	$4.42 \times 10^{22}$	$4.42 \times 10^{22}$
Atomic weight	28.09	144.63	72.60
Crystal structure	Diamond	Zincblende	Diamond
Density (g/cm <sup>-3</sup> )	2.33	5.32	5.33
Lattice constant (Å)	5.43	5.65	5.65
Melting point (°C)	1415	1238	937
Dielectric constant	11.7	13.1	16.0
Bandgap energy (eV)	1.12	1.42	99.0
Electron affinity, $\chi$ (V)	4.01	4.07	4.13
Effective density of states in conduction band, $N_c$ (cm <sup>-3</sup> )	$2.8\times10^{19}$	$4.7 \times 10^{17}$	$1.04 \times 10^{19}$
Effective density of states in valence band, $N_v$ (cm <sup>-3</sup> )	$1.04 \times 10^{19}$	$7.0 \times 10^{18}$	$6.0\times10^{18}$
Intrinsic carrier concentration (cm $^{-3}$ ) Mobility (cm $^2$ /V-s)	$1.5\times10^{10}$	$1.8 \times 10^6$	$2.4\times10^{13}$
Electron, $\mu_n$	1350	8500	3900
Hole, $\mu_p$	480	400	1900
Effective mass $\left(\frac{m^*}{m_0}\right)$			
Electrons	$m_I^* = 0.98$	0.067	1.64
	$m_t^* = 0.19$		0.082
Holes	$m_{lh}^* = 0.16$	0.082	0.044
	$m_{hh}^* = 0.49$	0.45	0.28
Effective mass (density of states)			
Electrons $\left(\frac{m_n^*}{m_0}\right)$	1.08	0.067	0.55
Holes $\left(\frac{m_p^*}{m_0}\right)$	0.56	0.48	0.37



